

# ESDA6V8UR

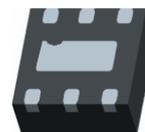
## 3-Lines, Uni-directional, Ultra-low Capacitance, Transient Voltage Suppressors

### Descriptions

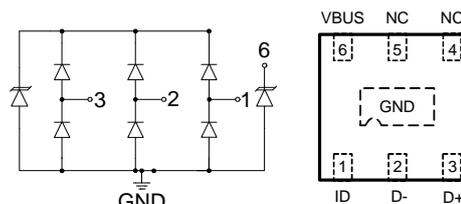
The ESDA6V8UR is a transient voltage suppressors (TVS) which provide a very high level protection for sensitive electronic components that may be subjected to electrostatic discharge (ESD). It is designed to replace multilayer varistors (MLV) in consumer equipments applications such as mobile phone, notebook, PAD, STB, LCD TV etc.

The ESDA6V8UR was past ESD transient voltage up to ±8kV (contact) according to IEC61000-4-2 and withstand peak current up to 3A for 8/20us pulse according to IEC61000-4-5.

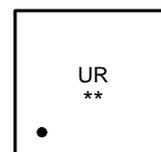
The ESDA6V8UR is available in DFN1.6\*1.6 package. Standard products are Pb-free and Halogen-free.



DFN1.6\*1.6



Pin configuration (Top view)



UR = Device code  
 \*\* = Week(01~52)

### Marking

### Features

- ID/D-/D+
  - Working voltage : 5V
  - Peak power (tp=8/20us) : 45W Max.
  - Peak current (tp=8/20us) : 3A Max.
  - Transient protection IEC61000-4-2 : ±15kV air  
: ±8kV contact
- VBUS
  - Working voltage : 12V
  - Peak power (tp=8/20us) : 155W Max.
  - Peak current (tp=8/20us) : 4.5A Max.
  - Transient protection IEC61000-4-2 : ±30kV air  
: ±30kV contact
- Ultra-low clamping voltage
- Low leakage current
- Small package

### Order information

Device	Package	Shipping
ESDA6V8UR-6/TR	DFN1.6*1.6	3000/Tape&Reel

### Applications

- Mobile phone
- PAD
- Notebook
- STB
- LCD TV
- Digital camera
- Other electronics equipments

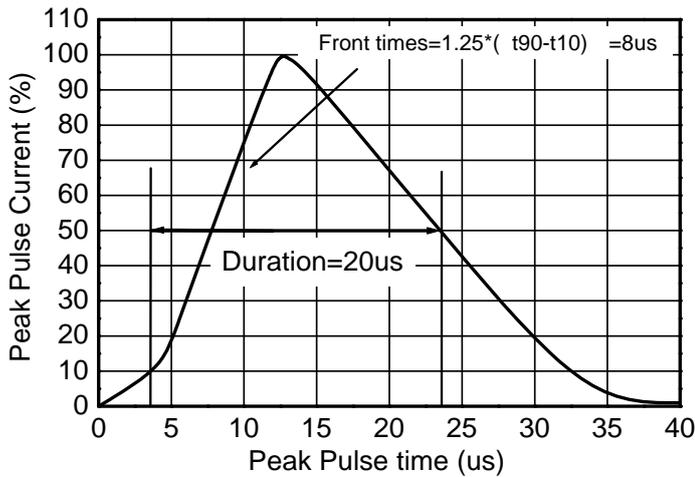
**Absolute maximum ratings**

Parameter	Symbol	Rating	Unit
Junction temperature	$T_J$	125	°C
Operating temperature	$T_{OP}$	-40~85	°C
Lead temperature	$T_L$	260	°C
Storage temperature	$T_{STG}$	-55~150	°C
<b>ID/D-/D+ TO GND</b>			
Peak pulse power (tp=8/20us)	Ppk	45	W
Peak pulse current (tp=8/20us)	Ipp	3	A
ESD voltage IEC61000-4-2 (Contact)	$V_{ESD}$	±8	kV
ESD voltage IEC61000-4-2 (Air)	$V_{ESD}$	±15	kV
<b>VBUS TO GND</b>			
Peak pulse power (tp=8/20us)	Ppk	155	W
Peak pulse current (tp=8/20us)	Ipp	4.5	A
ESD voltage IEC61000-4-2 (Contact)	$V_{ESD}$	±30	kV
ESD voltage IEC61000-4-2 (Air)	$V_{ESD}$	±30	kV

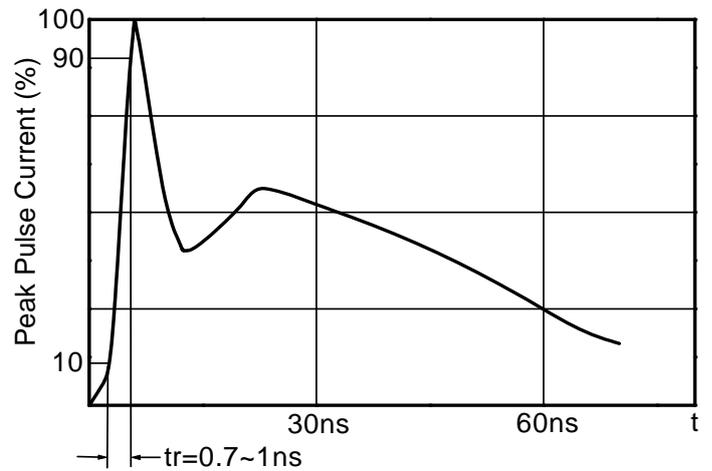
**Electronics characteristics (Ta=25°C, unless otherwise noted)**

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
<b>ID/D-/D+ TO GND</b>						
Reverse maximum working voltage	$V_{RWM}$				5	V
Reverse leakage current	$I_R$	$V_{RWM}=5V$			1	uA
Reverse breakdown voltage	$V_{BR}$	$I_T=1mA$	6.5	8.0	8.8	V
Forward voltage	$V_F$	$I_F=10mA$	0.55	0.9	1.25	V
Clamping voltage	$V_C$	Ipp=1A tp=8/20us			11	V
		Ipp=3A tp=8/20us			15	V
Junction capacitance	$C_J$	ID/D-/D+ TO GND		0.7	0.9	pF
<b>VBUS TO GND</b>						
Reverse maximum working voltage	$V_{RWM}$				12	V
Reverse leakage current	$I_R$	$V_{RWM}=12V$			50	nA
Reverse breakdown voltage	$V_{BR}$	$I_T=1mA$	15	16.5	18	V
Forward voltage	$V_F$	$I_F=10mA$	0.55	0.9	1.25	V
Clamping voltage	$V_C$	Ipp=1A tp=8/20us			21	V
		Ipp=4.5A tp=8/20us			35	V
Junction capacitance	$C_J$	VBUS TO GND		25	35	pF

ESDA6V8UR

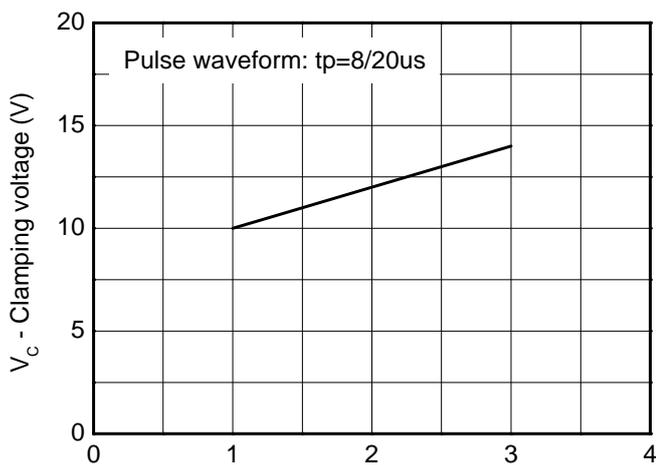


8/20us waveform

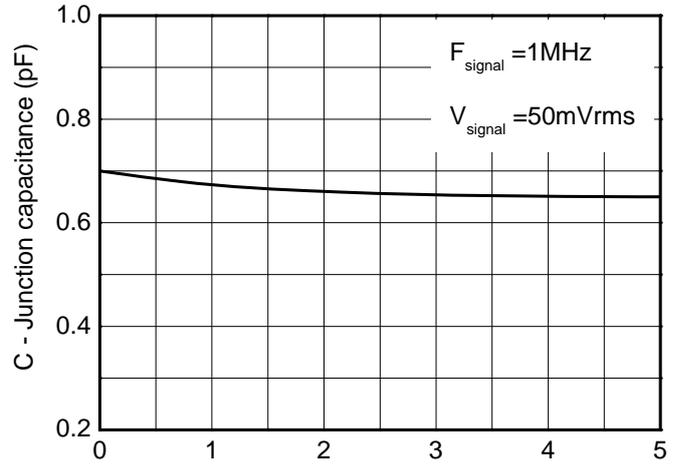


IEC61000-4-2 waveform

Typical characteristics (Ta=25°C, unless otherwise noted)



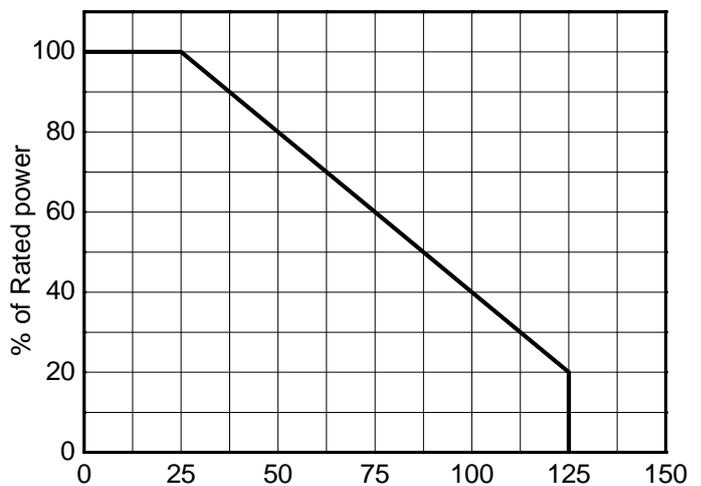
Clamping voltage vs. Peak pulse current  
ID/D-/D+ TO GND



Capacitance vs. Reverses voltage  
ID/D-/D+ TO GND

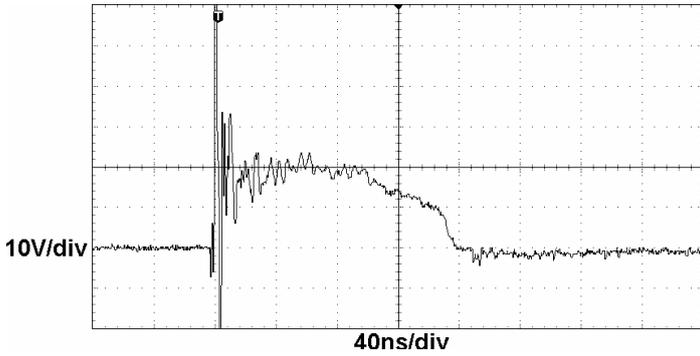


Non-Repetitive Peak Pulse Power vs. Pulse time  
ID/D-/D+ TO GND

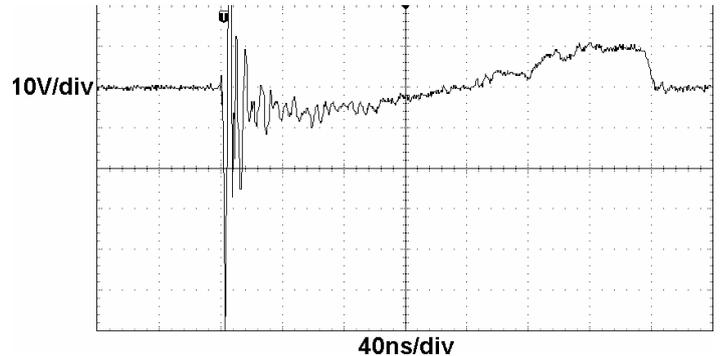


Power derating vs. Temperature  
ID/D-/D+ TO GND

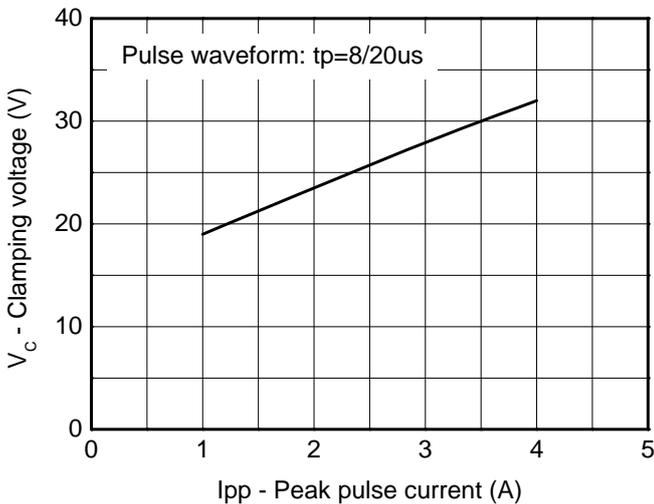
**ESDA6V8UR**



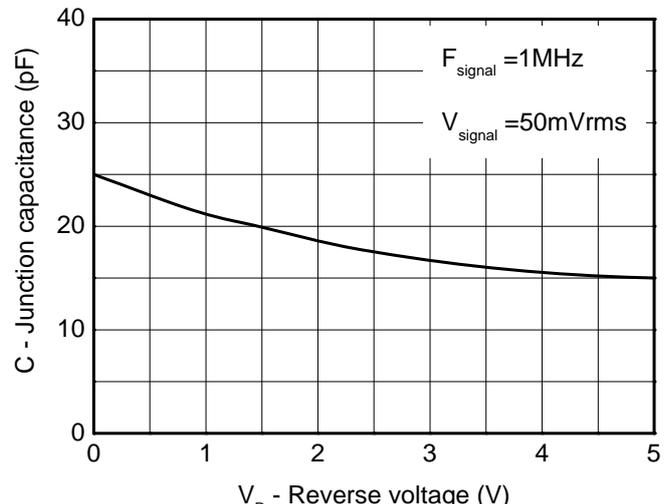
**ESD Clamping**  
**(IEC61000-4-2 +8kV contact)**  
**ID/D-/D+ TO GND**



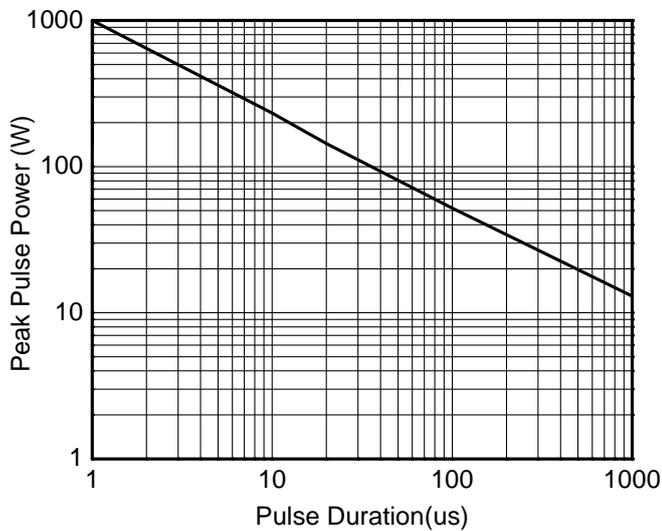
**ESD Clamping**  
**(IEC61000-4-2 -8kV contact)**  
**ID/D-/D+ TO GND**



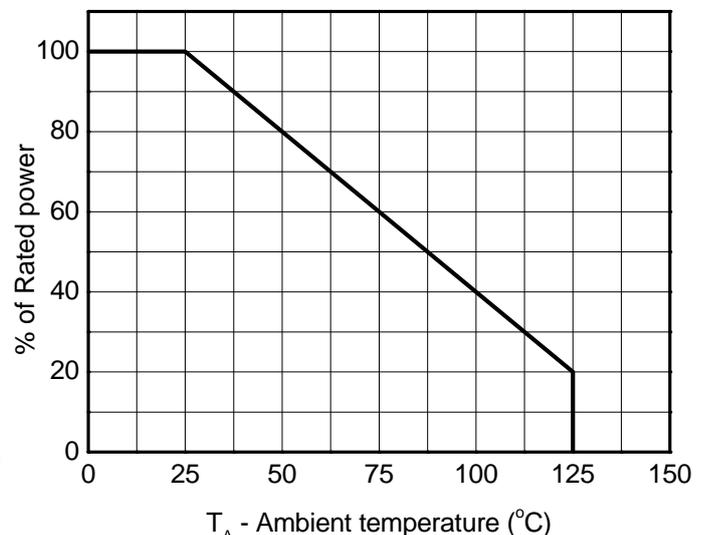
**Clamping voltage vs. Peak pulse current**  
**VBUS TO GND**



**Capacitance vs. Reverse voltage**  
**VBUS TO GND**

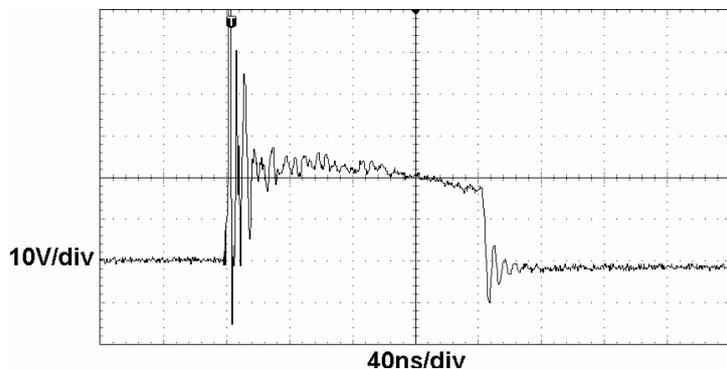


**Capacitance vs. Reverse voltage**  
**VBUS TO GND**

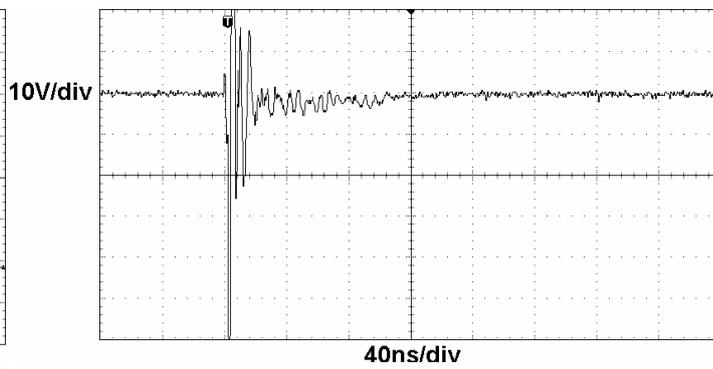


**Power derating vs. Temperature**  
**VBUS TO GND**

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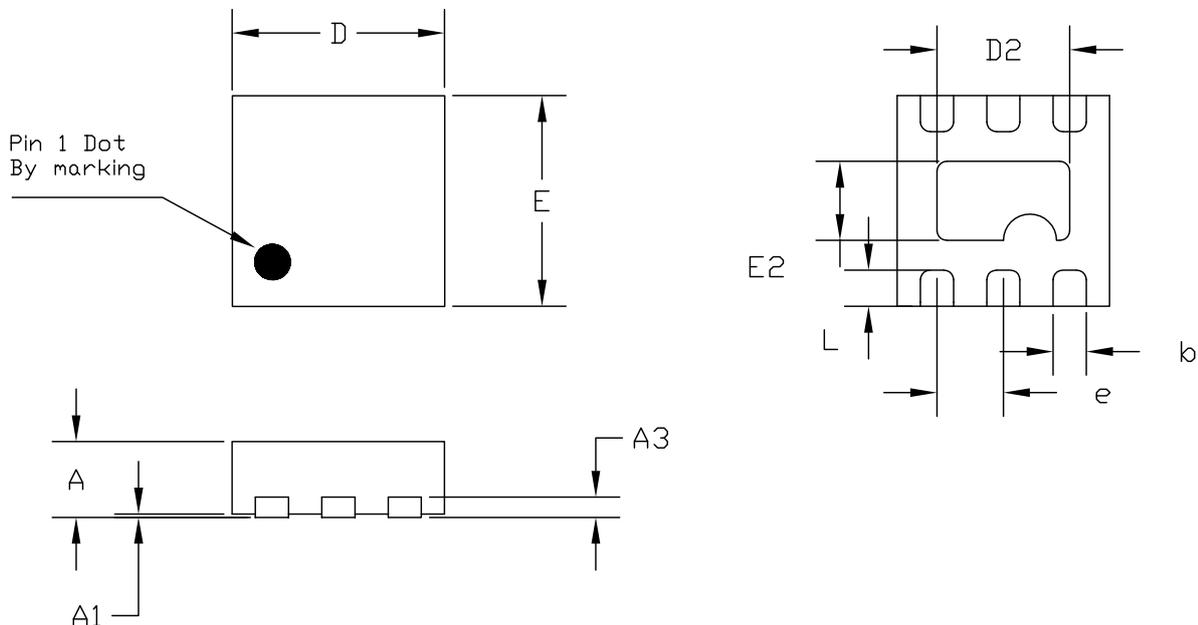
**ESD Clamping**  
**(IEC61000-4-2 +8kV contact)**  
**VBUS TO GND**



**ESD Clamping**  
**(IEC61000-4-2 -8kV contact)**  
**VBUS TO GND**

Package outline dimensions

DFN1.6\*1.6



Symbol	Dimensions in millimeter		
	Min.	Typ.	Max.
A	>0.50	0.55	0.600
A1	0.00	—	0.05
A3	0.15REF		
D	1.55	1.60	1.65
E	1.55	1.60	1.65
D2	0.90	1.00	1.05
E2	0.50	0.60	0.65
L	0.175	0.275	0.375
b	0.20	0.25	0.30
e	0.50 BSC		

Recommend PCB Layout (Unit: mm)

